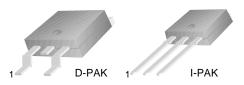


### **MJD44H11**

# General Purpose Power and Switching Such as Output or Driver Stages in Applications D-PAK for Surface Mount Applications

- Load Formed for Surface Mount Application (No Suffix)
- Straight Lead (I-PAK, "- I" Suffix)
- Electrically Similar to Popular MJE44H
- · Fast Switching Speeds
- Low Collector Emitter Saturation Voltage



1.Base 2.Collector 3.Emitter

## **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	80	V
$V_{EBO}$	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current (DC)	8	Α
I <sub>CP</sub>	Collector-Current (Pulse)	16	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	20	W
	Collector Dissipation (T <sub>a</sub> =25°C)	1.75	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	*Collector-Emitter Sustaining Voltage	$I_C = 30 \text{mA}, I_B = 0$	80			V
I <sub>CEO</sub>	Collector Cut-off Current	$V_{CE} = 80V, I_{B} = 0$			10	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{BE} = 5V, I_{C} = 0$			50	μΑ
h <sub>FE</sub>	*DC Current Gain	$V_{CE} = 1V, I_{C} = 2A$	60			
		$V_{CE} = 1V$ , $I_C = 4A$	40			
V <sub>CE</sub> (sat)	*Collector-Emitter Saturation Voltage	$I_C = 8A, I_B = 0.4A$			1	V
V <sub>BE</sub> (on)	*Base-Emitter ON Voltage	$I_C = 8A, I_B = 0.8A$			1.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.5A$		50		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, f = 1MHz		130		pF
t <sub>ON</sub>	Turn ON Time	I <sub>C</sub> = 5A		300		ns
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = 0.5A$		500		ns
t <sub>F</sub>	Fall Time			140		ns

<sup>\*</sup> Pulse Test: PW≤300μs, Duty Cycle≤2%

# **Typical Characteristics**

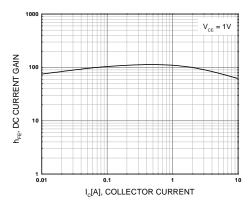


Figure 1. DC current Gain

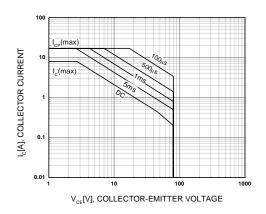


Figure 2. Safe Operating Area

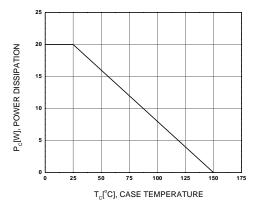
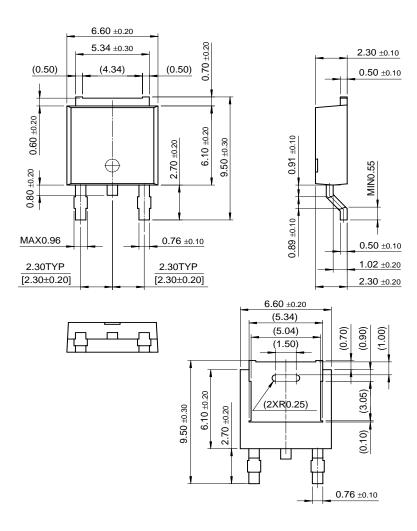


Figure 3. Power Derating

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# **Package Demensions**

# D-PAK



Dimensions in Millimeters

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